NSN 5961-01-027-8752

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-027-8752 **Inclosure Material:** Metal **Overall Length:** Between 0.495 inches and 0.545 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.420 inches **Function For Which Designed:** Rectifier **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited and 400.0 working peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 8.00 amperes forward current, average of standard range **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: